## Heat conduction and W iedem ann-Franz Law in disordered Luttinger Liquids

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W e consider heat transport in a Luttinger liquid (LL) with weak disorder and study the Lorenz number for this system . W e start at a high-T regim e, and calculate both the electrical and therm al conductivities using a memory function approach. The resulting Lorenz number L is independent of T but depends explicitly on the LL exponents. Low ering T, how ever, allows for a renorm alization of the LL exponents from their bare values by disorder, causing a violation of the W iedem ann-Franz law. Finally, we extend the discussion to quantum wire system s and study the wire size dependence of the Lorenz number.

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The W iedem ann-Franz (W F) law states that for electrons elastically scattered by in purities the ratio of the therm al () and electrical ( $_{\rm c}$ ) conductivities norm alized by T is a universal number  $L_0 = = _{\rm c}T = ^2=3e^2$  called the Lorenz number. This law is obeyed for electrons in conventionalm etals [1], and inclusion of electronic interactions that lead to the standard Landau Ferm i-liquid (FL) behavior does not modify  $L_0$  [2], as their e ect on and  $_{\rm c}$  scales away when the particle-particle scattering rate is much smaller than the in purity scattering rate.

A fundamental question arises whether the W F law survives in strongly correlated electron system swith non-FL ground states. Interest in this question has been recently revived by an observation of violation of W F law in high- $T_c$  cuprates [3] which are widely believed to be non-FL system s. An important and tractable example of a non-FL is a one-dimensional (ld) Luttinger liquid (LL) with separate charge () and spin () bosonic collective excitations [4{6] instead of fermionic quasiparticles. Heat being carried by both spin and charge excitations, there is a potential for violation of W F law in a LL. However, a potential com plication in the LL case is that even a weak disorder can cause Anderson localization [7{11].

Experimentally, thermal transport in (quasi-)1d has been investigated in spin-chain, [12] spin-Peierls, [13] and spin-ladder materials [14]. There are also some early m easurements of heat conduction in quasi-1d organic conductors [15]. Theoretically, although  $_{c}(T)$  in the LLs has been extensively discussed [16{18] with memory function m ethods [19], the therm al conductivity and the WF law have only been addressed in two contexts. First, K ane and Fisher (KF) [20] exam ined spinless LLs with a single strong in purity for repulsive electronic interactions, and found a T-independent but nonuniversal Lorenz num ber L<sup>(KF)</sup>. The generalization of this problem to the bulk disorder case is how ever not straightforw and [21] (as discussed below). Second, Fazio et al. [22] and K rive [23] have studied therm altransport in a m esoscopic 1d wire connected to leads. They showed that even for a clean wire the contact with leads causes violation of the WF law except at su ciently low T. However, the e ect of backward scattering by nite-density in purities has not been considered in the latter case.

In this letter, we rst exam ine the W F law for an in nite LL with a nonzero concentration of in purities. Unlike KF, we calculate (T) and  $_{\rm c}$ (T) in the high-T regime where in purity scattering can be treated by the memory function method [19,16]. The resulting Lorenz number is independent of T but depends on the LL exponents. It diers from the one obtained by KF.As T goes down, we show that the Lorenz number acquires T dependence as the consequence of instability towards Anderson localized state. Such a violation of the W F law is in sharp contrast to the higher-d FL situation. Finally we exam ine the e ects of contact in a realistic quantum wire measurement and discuss the wire-size dependence of the Lorenz number.

C onductivities from M emory function m ethod. A LL of spin-1/2 ferm ions in the presence of impurities is described by the following H am iltonian [11]

$$H = H_{LL} + H_{imp} = dx H (x); \qquad (1)$$

Ζ

$$H_{LL} = \frac{X}{\sum_{i=1}^{L} \frac{dx}{2}} \frac{dx}{2} u_{i}K_{i}[i(x)]^{2} + \frac{u_{i}}{K_{i}} \theta_{x}(x)^{2}; (2)$$

$$H_{inp} = \frac{1}{2} dx (x) \theta_{x}$$

$$Z = \frac{1}{2} dx (x) \theta_{x}$$

$$+ dx \frac{1}{a} e^{i \frac{p}{2}} (x) \cos[i \frac{p}{2}] (x)] + Hc.; (3)$$

where K<sub>i</sub> are the LL exponents, u<sub>i</sub> the velocities of the excitations, a the lattice constant, and <sub>i</sub>(x) and <sub>i</sub>(x) are canonical momenta and coordinates, respectively. (x) in Eq. (3) is the  $2k_F$  component of the impurity potential, assumed to have a Gaussian distribution with zero average, (x) (x<sup>0</sup>) = D (x x): (x) is the forward scattering component. The charge and heat currents  $J_c = dx J_c(x)$  and  $J_Q = dx J_Q(x)$  are obtained from the continuity equations  $\theta_x J_c(x) + \theta_t n(x) = 0$  and  $\theta_x J_Q(x) + \theta_t H(x) = 0$ , where n(x) =  $\frac{p}{2}\theta_x$  (x) is the electron density operator. We nd

$$J_{c}(x) = \frac{P}{2}u K (x);$$
 (4)

$$J_Q(x) = u^2 Q_x u^2 Q_x + J(x);$$
 (5)

where J (x) =  $p \overline{2}u K$  (x) (x): We note that the transform ation  $\sim (x) = (x)$   $p \overline{2}_{u}^{K} R_{x}^{R}$  (x<sup>0</sup>)dx<sup>0</sup> elim integrates from both H<sub>imp</sub> and J<sub>Q</sub>, implying a nulle ect of (x) on c and . Thus we set (x) 0 hearafter. Eqs. (4) and (5) also show that the heat and charge current operators are quadratic and linear in boson operators, respectively. This is crucial in resulting in deviation of the Lorenz number from the universal number at high T even for spinless ferm ion case as shown below.

In the absence of impurities, both  $J_c$  and  $J_Q$  are conserved currents. In fact,  $J_Q$  is (up to a prefactor) the total momentum of the system, and its conservation results from translational invariance. W ith impurities, neither  $J_c$  and  $J_Q$  are conserved and nite conductivities can be expected [18]. At su ciently high T, quantum e ects are cut o by inelastic therm al processes, and disorder scattering can be treated within the Born approximation. This yields conductivities to leading order in D<sup>-1</sup>. A convenient form alism to do this is the memory function method [19,17,18], in which the nite-frequency electrical and therm al conductivities are expressed in terms of the memory functions M<sub>j</sub>(!) =  $\int_{1}^{1} ! \int_{1}^{1} hF_{j};F_{j}ii! = \int_{1}^{1} (j = c;Q)$  as

$$_{c}(!) = ie^{2} _{c}[! + M_{c}(!)]^{1};$$
 (6)

$$(!) = i_{Q} T^{1} [! + M_{Q} (!)]^{1};$$
(7)

with  $j = T_0^{R_{1=T}} d h J_j(0)^y J_j(i)$  i the current static suggesptibilities,  $F_j(x) = [J_j(x);H]$ , and  $h F_j;F_j i I_j =$ 

 $\int_{c}^{K} dx dx^{0} dt e^{i!t} hF_{j}(x;t);F_{j}(x^{0};0) J_{H}^{j}$ : To leading order in D, both c and Q take their pure LL values,  $\frac{2}{3}u$  K;  $\frac{2}{3}(u + u)T^{2}$ , and

$$\begin{split} hhF_{j};F_{j}ii_{!} & I \quad 2^{K_{t}+2} (a)^{K_{t}-2} u^{K} u^{K} \quad A_{j}(!) \\ sin \quad \frac{K_{t}}{2} \quad B \quad \frac{K_{t}}{2} \quad \frac{i!}{2 T}; 1 \quad K_{t} \quad T^{-j}; \quad (8) \end{split}$$

where K<sub>t</sub> = K + K ; B (x;y) is the Euler B eta function,  $_{c} = 1$  K<sub>t</sub>,  $_{Q} = _{c}$  2, A<sub>c</sub>(!) = K<sup>2</sup>u<sup>2</sup> = ; and A<sub>Q</sub>(!) =

 $(K_t^2=4+ !=2 T^2 (K u^2 + K u^2)=[K_t (K_t + 1)]: In-serting Eqs. (8) into Eqs. (6-7), and after some straight-forward algebra, we nd that the dc conductivities become$ 

$$_{c}(T)' = \frac{2e^{2}(K_{t})}{{}^{2}(K_{t}=2)} \frac{a}{D} = \frac{2aT}{u} = e^{2} l_{el}(T);$$
 (9)

(T) 
$$\frac{2 T}{9} \frac{1 + K_{t}}{K_{t}} \frac{(u + u)^{2}}{u^{2}K + u^{2}K} \frac{(K_{t})}{2(K_{t}=2)}$$
  
$$\frac{a}{D} \frac{2 aT}{u} \frac{2 K_{t}}{2(K_{t}=2)} / C_{v}(T) l_{e1}(T); \quad (10)$$

where D =  $(2D \ a= u^2)(u = u)^K$  is a dimensionless disorderparameter [11], (x) the G am m a function, C<sub>v</sub> (T) / T the speci c heat of a pure LL, and  $l_{e1}(T)$  the elastic mean free path [8]. Both <sub>c</sub> and exhibit power-law behavior in T with nonuniversal exponents.

Lorenz num ber at high T. From Eqs. (9) and (10), one has

$$L = \frac{1}{cT} = \frac{2}{9e^2} \frac{(u + u)^2}{u^2 K + u^2 K} \frac{1 + K_t}{K_t}$$
(11)

K ,K ,u and u are bare intrinsic parameters, so L is independent of T, and a generalized W F law is obeyed. In the noninteracting case, K = K = 1, u = u = v\_F, the universal Lorenz number L = L<sub>0</sub> is recovered from Eq. (11).

The result (11) can be reduced to the spinless LL case, by making  $u = u = u, K = K = K \cdot W$  e obtain

$$L^{0} = (^{2} = 9e^{2}) (K^{2} + 2K^{1}):$$
 (12)

It follows that  $L^0 < L_0$  for an attractive interaction case K > 1, as a result of tendency towards a superconducting state with high electrical conduction but poor therm al conduction; W hile for a repulsion case K < 1,  $L^0 > L_0$ , indicating tendency towards a weakly pinned charge density wave (CDW) state with better heat transport than charge transport. It is instructive to compare  $L^{0}$  with  $L^{(KF)} = (^{2}=e^{2})(K^{2} + 2K)^{1}$  obtained by KF for a single strong in purity at K < 1 [20]. We see that  $L^{0} = L^{(KF)} = 2(K = 1)^{2} = 9K^{2}(K + 2)$  0. From physical point of view , L  $^{\rm (K\ F\ )}$  and L  $^0$  can be roughly understood as the results for a strongly pinned and a weakly pinned CDW phase, respectively, so that we should expect a larger  $L^{(K F)}$  than  $L^0$ . This puzzle can be resolved by noting that som e H am iltonian term s causing heat but no charge conduction are neglected in the derivation of the tunneling Ham iltonian used to calculate L (K F ) [20]. Including these terms explicitly for K = 1=2 indeed leads to [20]  $\Gamma^{(K F)} = \frac{3}{2} L^{(K F)} > L^{0}$ .

We would also like to remark that the single strong in purity case considered by KF corresponds to a low energy xed point which cannot be reached from the lim it of weak in purity scatterers at high concentration c we consider [21]. The KF xed point is realized when the renormalized in purity strength  $t_B$  (l) =  $e^{(2 \ 2K \ )1} t_B$  (0) becomes of the order of the high energy cuto W u=a. This requires the renormalized length  $ae^{1^\circ} = a \ W = t_B \ (0) \ J^{1=(2 \ 2K \ )}$  to remain still much smaller than the inter-in purity distance 1=c. In the high in purity concentration lim it, c ! 1,  $t_B$  ! 0 with D =  $ct_B^2$  xed, obviously such regime cannot be observed.

Lorenz number with decreasing T. The enhanced quantum interference e ects, which are responsible for occurrence of the Anderson localization at T <  $T_{\rm loc}$  = u = $l_{\rm loc}$  ( $l_{\rm loc}$  = aD  $^{1=(3~K~t)}$  [11]), lead to renormalization of K , K and D. Now we study the in uence of such renormalization on L for T still much larger than  $T_{\rm loc}$ , so that a perturbative renormalization group (RG) theory can be used. We rst neglect renormalization of K and K by D. The RG ow equation determining the renormalization ofD reads [11] dD (l)=dl= (3 $K_{\rm t})$ D (l); which leads to

$$D(1)=D = e^{(3 K_t)1}$$
 (13)

It is clear that K t = 3 de nes a m etal-insulator transition (M II ) line: for K  $_{\rm t}$  < 3, D (1) grows exponentially with renorm alized length, and the Anderson localization will take place eventually; W hereas for  $K_t > 3$ , D (1) ow s to zero, corresponding to a delocalized phase. By de ning a T-dependent scale 1 (T) from  $ae^{1(T)} = u = (2 T) =$  $l_{th}$  (T) ( $l_{th}$  the therm al length), we see that Eq. (13) yields  $(a = D) (2 aT = u)^{2 K t} = ae^{1 (T)} = [D(1)];$  which allows for a simple RG interpretation for  $_{\rm c}$  and in Eqs. (9-10): They can be obtained by applying the RG ow up to the scale 1 (T) at which T becomes order of the energy cuto u =a. At this scale, therm all e ects suppress quantum e ects, and the use of the memory function method is justied. One can then perform a memory function calculation in which the bare param eters D and a are replaced by D (1) and  $ae^1$ , respectively.

A sim ilar analysis can be made for inclusion of renormalization of K and K by D. We start from the bare parameters K (0), K (0) and D (0) and follow their RG ow, being described by Eqs. (3.4) in Ref. [11], up to the scale 1 (T). Since D (1) 1 still holds for T  $T_{\rm loc}$ , but the quantum phase coherence has started to lose, Eqs. (9-10) are valid again [24], but with the bare K and K replaced by the renorm alized ones, K (1) and K (1), respectively. The resulting RG-im proved L acquires T dependence through K and K, and the generalized W F law holding at high T breaks down. This is in contrast to a higher-d FL case, in which such a renorm alization is always negligible [2].

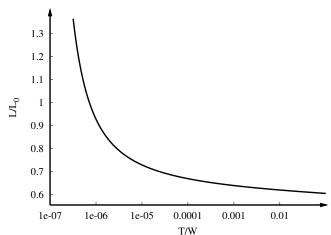


FIG.1. Lorenz number as a function of temperature close to the MIT line for spinless fermions. W u=a is a high energy cuto . The initial conditions are K (0) = 3=2;D (0) =  $10^{-2}$ .

W e proceed with a discussion of the spinless ferm ion case for simplicity. The above analysis suggests that  $L^0$  in Eq. (12) as a function of the initial parameter K becomes

 $L(T) = ({}^{2}=9e^{2})f[K(1)]^{2} + 2[K(1)]^{1}g;$  (14)

where K (1) can be obtained from the RG ow equation

[11], dK (l)=dl =  $K^2$  (l)D (l)=2. For a generic initial K away from the M IT line, the RG ow line in the K-D plane is almost vertical, and the deviation of L from its high-T value is in order of D which is insignic cant unless T becomes close to  $T_{\rm loc}$ . A lternatively, considering the second order terms in D in  $_{\rm c}$  and one also obtains a T-dependent power-law correction term to L (T) with the exponent predicted by the RG m ethod.

However, in the vicinity of the M IT line, the RG ow is no longer vertical, leading to a faster variation of L with T. K (l) K j is found to be proportional to D (l) D, indicating that L (T) shown in Eq. (14) is system atic. L (T) for this case is shown in Fig.1. We em – phasize that such a behavior is not expected in a higherd FL case, in which the Lorenz number is constant even close to the M IT point [2].

Lorenz number in dirty quantum wires. An experim ental realization for the m easurem ent of the transport properties of a LL is through a nite size wire connected to leads [25] or a carbon nanotube [26]. The theory presented here for a bulk material needs to be modi ed, as the boundary condition in posed by the contact is shown [27,22] to drastically in uence the transport through the wire. Charge crosses the contact in terms of pieces of fractional charges [28], whereas heat is carried by plasm on m odes and they cross the contact like w aves passing through barriers [22]. The Lorenz num ber will obtain a nontrivial wire size dependence as shown below. For sim plicity we only discuss about spinless LL wires, and leave the discussion of the spinful case for a future publication [29]. Besides, we follow Ref. [27] and model the leads as 1d noninteracting FLs.

We rst brie y recall the clean wire case. The electrical conductance G is purely from the contact and is quantized [27],  $G = G_0 = e^2=2$  (for h = 1), which implies a perfect transmission of the total charge after a long time (dc) measurement [28]. The mism atch of the plasm on wave velocities at the two sides of the contact leads to T-dependent thermal conductance K<sub>th</sub> normalized by T [22], which, at low temperatures T u=d (d the wire size), asymptotically approaches to a constant K<sub>th</sub>=T ' =6 [22]. The W F law is typically violated for a generic T and is restored at T u=d.

Let us now turn to the case of a wire with in purities. We consider the case of  $l_{\rm bc}$  being much larger than d and/or  $l_{\rm th}$  so that we can neglect Anderson localization. The total electrical resistance is the sum of the contact resistance G<sub>0</sub><sup>1</sup> and the wire resistance G<sub>w</sub><sup>1</sup><sub>ire</sub>, resulting in the following total conductance,

$$G = (G_0^{1} + G_{wire}^{1})^{1} :$$
 (15)

 $G_{\,w\,\,\rm ire}$  depends on the relative values of the two length scales d and  $l_{\rm th}$  (T ).

1) At d  $l_{th}$  (T u=d), a simple O hm law holds for the electrical conductance, i.e.,  $G_{wire} = (T)=d =$  $G_0 2 l_{el}=d with$  (T) and  $l_{el}$  being found in Eq. (9). Eq. (15) reduces, ford  $l_{el}(T)$ , to M asbv'sperturbation result [30], G '  $G_0$  [1 d=(2  $l_1$ )]; and, for d  $l_{e1}$ (T), crosses to the D rude form ula. In this regime, the thermal conductance of even a clean wire, K<sub>th</sub>, from Eq. (9) of Ref. [22], depends on the details of the barrier, so that the thermal conductance of the dirty wire becomes a rather non-universal function of disorder, wire size, and temperature [29].

2) At d  $l_{th}$  (T u=d), Eq. (9) of Ref. [22] indicates that heat is carried by plasm on modes of wavelength much larger than the distance between the contacts, and therm alconductivity of the clean wire become es universal. In this regime, we can make use of the T , u=d equivalence [31,30] to obtain an explicit d-dependent Lorenz number. A coording to 0 gata and Fukuyama, the nite size e ect can be taken into account within the mem ory function form alism by replacing ! in Eqs. (6) and (7) by i2u=d. This leads to

G (d) = 
$$\frac{ue^2}{2u + 2uC_c(u;K)}$$
 (16)

$$K_{th} (d) = \frac{uT}{3} \frac{1}{2u + 2uC_{th} (u; K) (d)};$$
(17)

with (d) =  $(d=l_{acc})^{3 \ 2K}$ , and  $C_c(u;K)$  and  $C_c(u;K)$  being easily found by comparing Eqs. (16) and (17) with Eqs. (9) and (10). In writing down Eq. (16) we have carefully taken into account the screening of the electric eld coming from the leads [32]. We recover a universal Lorenz number in this regime in the absence of impurities in agreement with [22]. In the presence of impurities, Eqs. (16) and (17) immediately yield

L (d) ' L<sub>0</sub> 
$$\frac{1 + C_c(u; K)}{1 + C_{th}(u; K)}$$
 (d)  
(18)

which is a function of the wire size since  $C_c(u;K) \in C_{th}(u;K)$  in the presence of interactions. Thus, deviation from W F law is obtained in nite size systems with impurities even for T u=d.

Conclusion. We have investigated the WF law in a disordered LL system. At high T where therm all eccts cut o Anderson localization, the Lorenz number is constant in T, and, in the spinless ferm ion case, smaller (larger) than the universal  $L_0$  for attraction (repulsion) between the ferm ions. Its dependence on the LL exponents is different from the one obtained in a single strong in purity case [20]. As T goes down, Anderson localization e ects induce an interplay between disorder and electronic interactions, which is responsible for the violation of the WF law. W hen a dirty 1d w ire is connected to leads we nd the Lorenz number becom es a function of the w ire length.

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